

N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ☒ Surface-mounted package
- ☒ Low thermal resistance

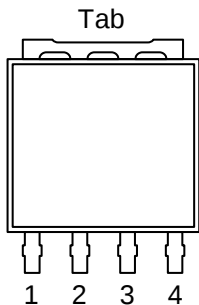
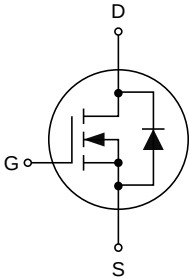
1.2 Applications

- ☒ Motor drivers
- ☒ DC/DC converter

1.3 Quick reference

- ☒ $BV \geq 100\text{ V}$
- ☒ $P_{tot} \leq 375\text{ W}$
- ☒ $I_D \leq 266\text{ A}$
- ☒ $R_{DS(ON)} \leq 2.3\text{ m}\Omega @V_{GS} = 10\text{ V}$
- ☒ $R_{DS(ON)} \leq 3.6\text{ m}\Omega @V_{GS} = 4.5\text{ V}$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1,2,3	Source	 Top View LFPAK 5×6	
4	Gate		
Tab	Drain		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	Drain-Source Voltage	$T_C=25^{\circ}\text{C}$	-	100	V
V_{GS}	Gate-Source Voltage	$T_C=25^{\circ}\text{C}$	-	± 20	V
I_D^*	Drain Current	$T_C=25^{\circ}\text{C}, V_{GS}=10\text{ V}$	-	266	A
		$T_C=100^{\circ}\text{C}, V_{GS}=10\text{ V}$	-	188	A
$I_{DM}^{*,***}$	Pulsed Drain Current	$T_C=25^{\circ}\text{C}, V_{GS}=10\text{ V}$	-	750	A
P_{tot}^*	Total Power Dissipation	$T_C=25^{\circ}\text{C}$	-	375	W
I_S	Diode Forward Current	$T_C=25^{\circ}\text{C}$	-	266	A
E_{AS}^*	Single Pulsed Avalanche Energy	$V_{DD}=50\text{ V}, L=1.0\text{ mH}$	-	1012	mJ
T_J, T_{stg}	Operating Junction and Storage Temperature Range		-55	175	$^{\circ}\text{C}$
$R_{\theta JA}^*$	Thermal Resistance-Junction to Ambient		-	57	$^{\circ}\text{C/W}$
$R_{\theta JC}$	Thermal Resistance-Junction to Case		-	0.4	

Notes:

* Surface mounted on 1 in² pad area, $t \leq 10\text{ sec}$.

** Pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.

*** Limited by bonding wire.

4. Marking Information

Product Name	Marking
KJ023N10LF	KJ023N10LF XXXXXX

5. Ordering Code

Product Name	Package	Reel Size	Tape Width	Quantity
KJ023N10LF	LFPK 5×6	13"	12 mm	5000

Note: KUAJIEXIN defines "Green" as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC/JEDEC J-STD-020C)

6. Electrical Characteristics (T_A=25°C unless otherwise noted)

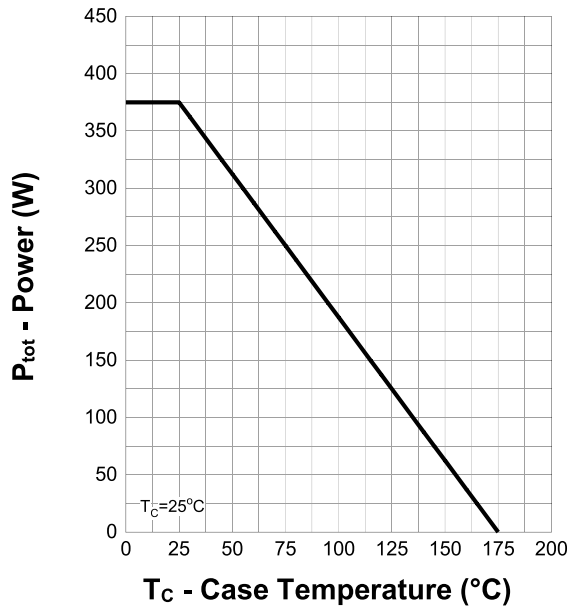
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0 V, I _{DS} =250 μA	100	-	-	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250 μA	1	-	2	V
I _{DSS}	Drain Source Current	V _{DS} =80 V, V _{GS} =0 V	-	-	1	μA
I _{GSS}	Gate Leakage Current	V _{DS} =0 V, V _{GS} =±20 V	-	-	±100	nA
R _{DS(ON)} ^a	On-State Resistance	V _{GS} =10 V, I _{DS} =30 A	-	1.95	2.3	mΩ
		V _{GS} =4.5 V, I _{DS} =20 A	-	2.8	3.6	
Diode Characteristics						
V _{SD} ^a	Diode Forward Voltage	V _{GS} =0 V, I _{SD} =30 A	-	-	1.3	V
t _{rr}	Reverse Recovery Time	V _{GS} =0 V, I _{SD} =30 A, dI _{SD} /dt=100 A/μs	-	83	-	ns
Q _{rr}	Reverse Recovery Charge		-	155	-	nC
Dynamic Characteristics ^b						
C _{iss}	Input Capacitance	V _{DS} =50 V, V _{GS} =0 V, f=1 MHz	-	5266	-	pF
C _{oss}	Output Capacitance		-	1003	-	
C _{rss}	Reverse Transfer Capacitance		-	16	-	
t _{d(on)}	Turn-on Delay Time	V _{DS} =50 V, V _{GEN} =10 V, R _G =3.9 Ω, R _L =1.66 Ω, I _{DS} =30 A	-	12	-	ns
t _r	Turn-on Rise Time		-	36	-	
t _{d(off)}	Turn-off Delay Time		-	94	-	
t _f	Turn-off Fall Time		-	77	-	
Gate Charge Characteristics ^b						
Q _g	Total Gate Charge	V _{DS} =50 V, V _{GS} =10 V, I _{DS} =30 A	-	106	-	nC
Q _{gs}	Gate-Source Charge		-	20	-	
Q _{gd}	Gate-Drain Charge		-	24	-	

Notes:

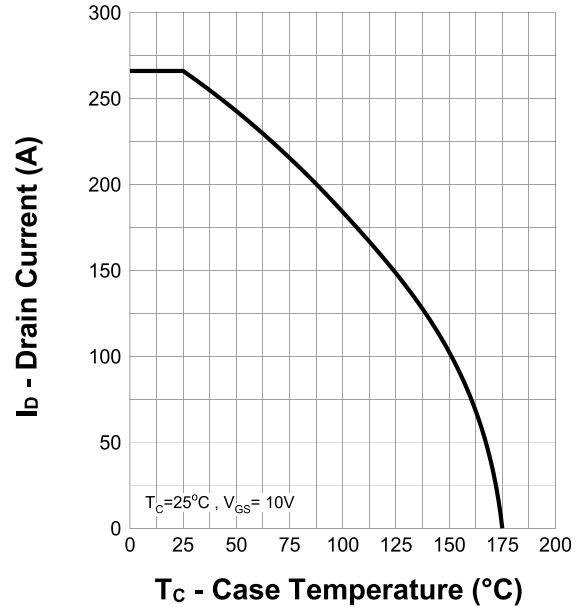
- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
- Guaranteed by design, not subject to production testing.

7. Typical Characteristics

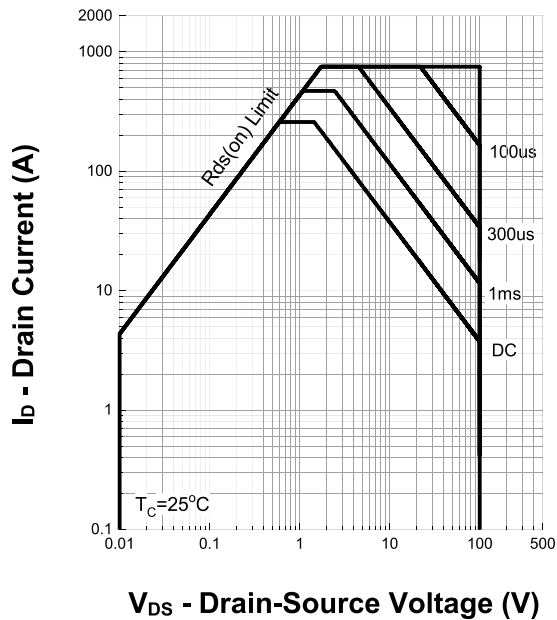
Power Capability



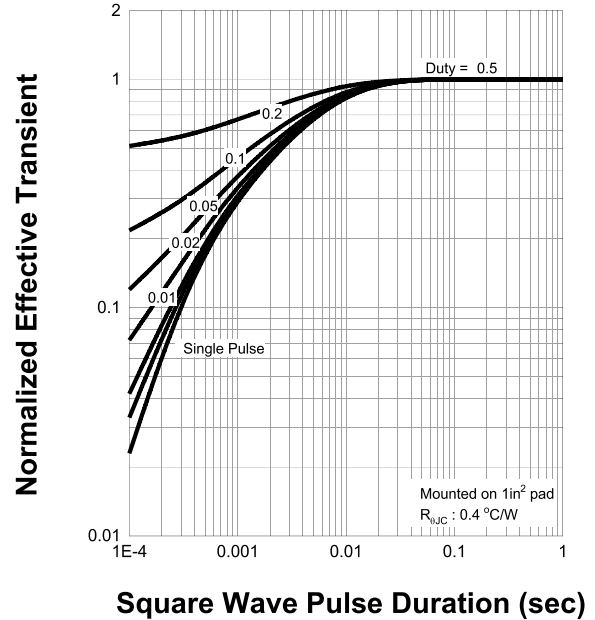
Current Capability



Safe Operating Area

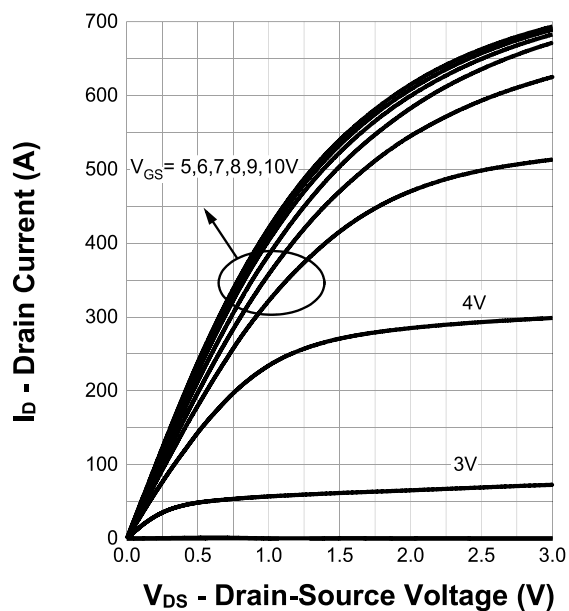


Transient Thermal Impedance

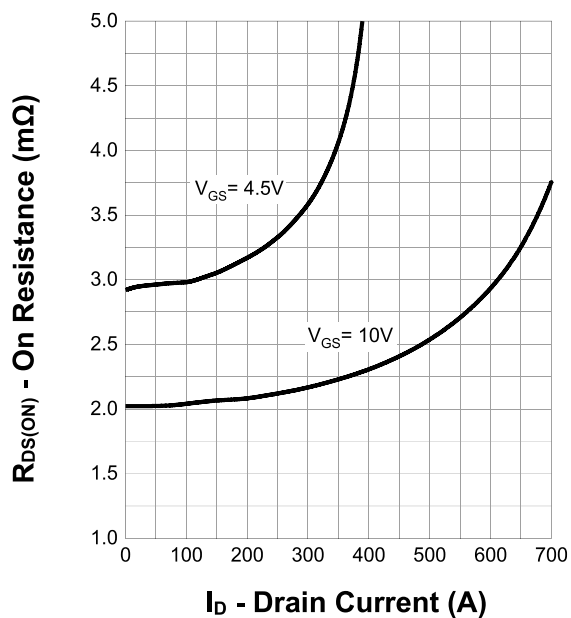


7. Typical Characteristics (cont.)

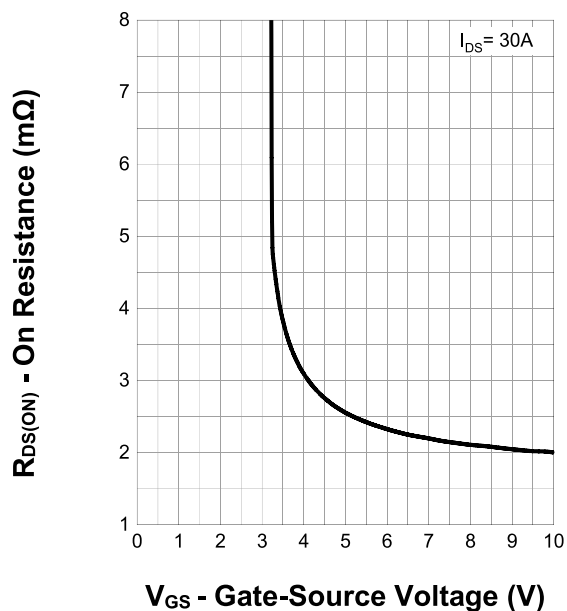
Output Characteristics



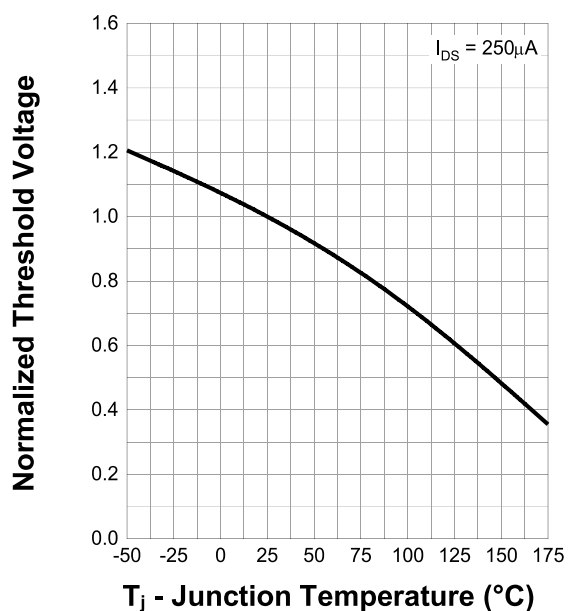
On Resistance



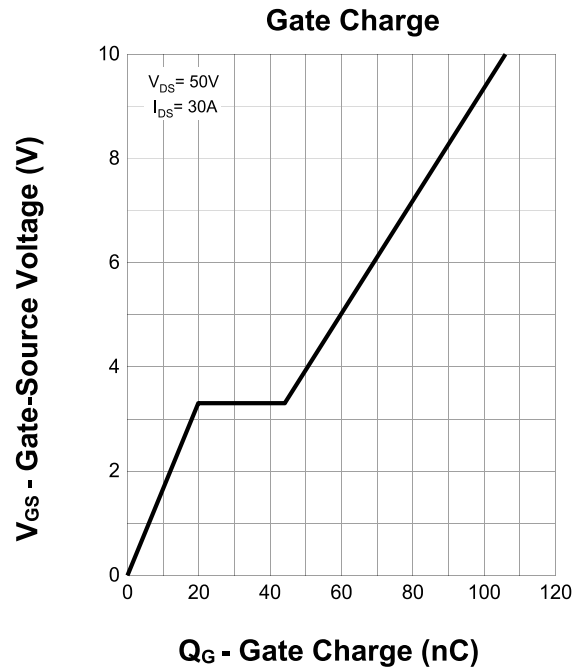
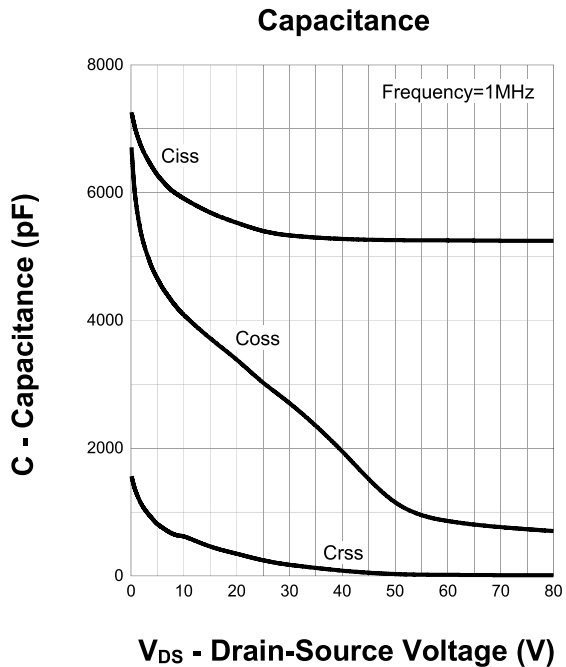
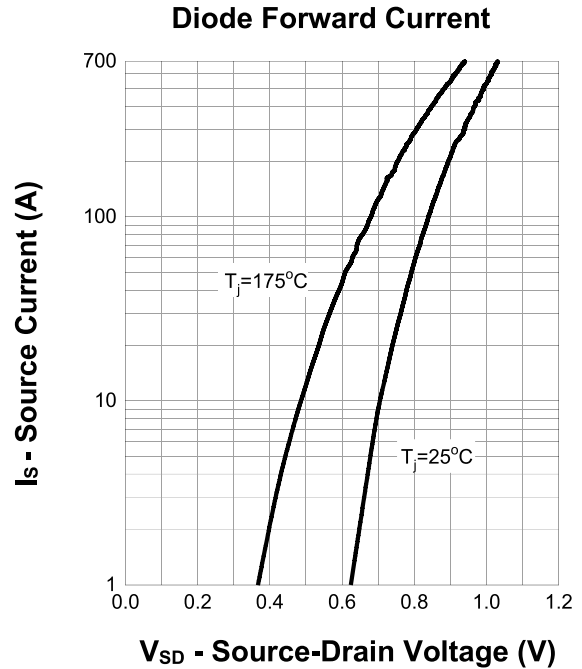
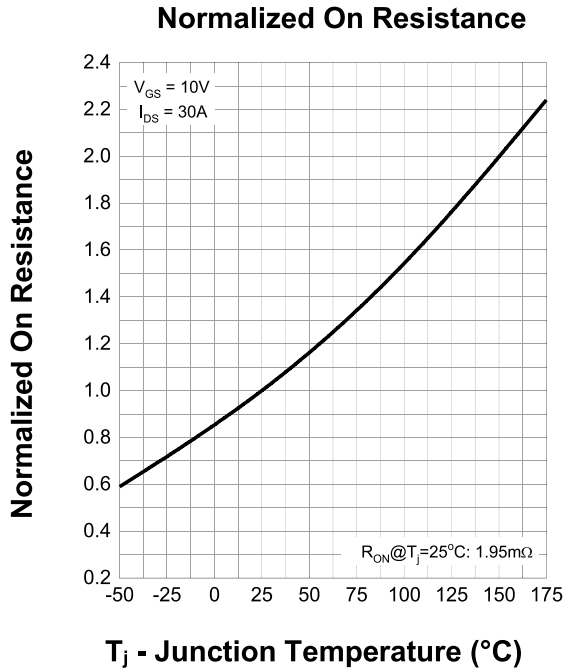
Transfer Characteristics



Normalized Threshold Voltage

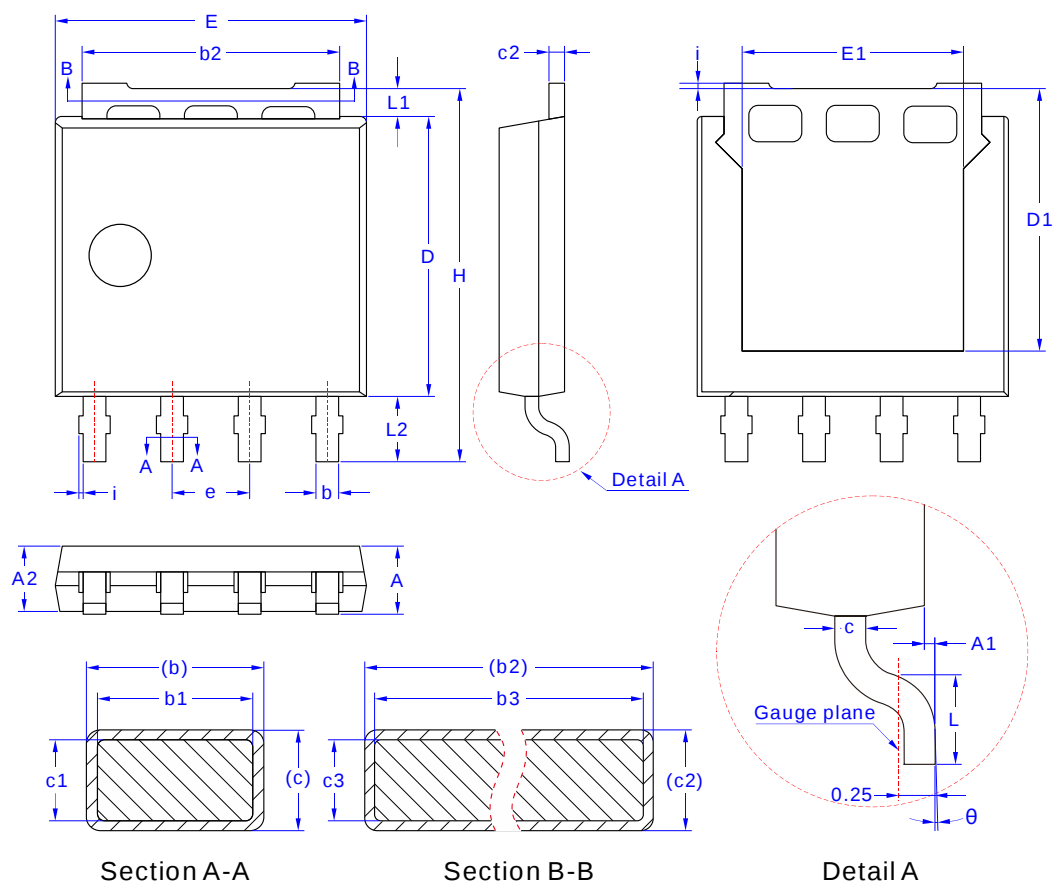


7. Typical Characteristics (cont.)



8. Package Dimensions

LFAK 5×6 Package



Symbol	Diminsions in Millimeters	
	MIN	MAX
A	1.00	1.30
A1	0	0.15
A2	0.98	1.12
b	0.35	0.50
b1	0.32	0.46
b2	4.02	4.41
b3	4.00	4.37
c	0.19	0.25
c1	0.17	0.23
c2	0.24	0.30
c3	0.22	0.28

Symbol	Dimensions in Millimeters	
	MIN	MAX
D	4.45	4.70
D1	-	4.45
E	4.95	5.30
E1	3.50	3.70
e	1.27 BSC	
H	5.95	6.25
i	-	0.25
L	0.40	0.85
L1	0.27	0.57
L2	0.80	1.30
θ	0°	8°